



Silicon Epitaxial Planar Switching Diode

SOD323

1. Features

• Low leakage current: typ. 3 nA

• Switching time: typ. 0.8 µs

• Continuous reverse voltage: min. 75 V

• Repetitive peak reverse voltage: min. 85 V

• Repetitive peak forward current: max. 500 mA.

2. Mechanical Data

- Case:Molded Plastic,SOD323 .
- Epoxy:UL 94V-0 rate flame retardant.
- Terminals:Plated Leads Solderable per MIL-STD-750,Method-2026.
- Marking:D4.
- Marking:marked on body.



Electrical Characteristics Rating at 25°C ambient temperature unless otherwise specified.





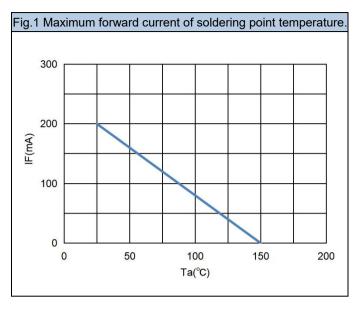
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Characteristic		Symbol	Value	Unit
Repetitive Peak Reverse Voltage		V_{RRM}	85	V
Reverse Voltage		V_R	75	V
Continuous Forward Current		I _F	200	mA
Repetitive Peak Forward Current		I _{FRM}	500	mA
Non-Repetitive Peak Forward Current	t = 1 μs		4	
	t = 1 ms	I _{FSM}	1	Α
	t = 1 s		0.5	
Total Power Dissipation		P _{tot}	200	mW
Junction Temperature		T_J	-65 to+150	°C
Storage Temperature Range		T _{stg}	-65 to+150	°C

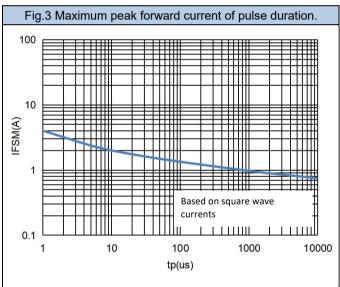
4. Electrical Characteristics (T_A =25 $^{\circ}$ C unless otherwise noted)

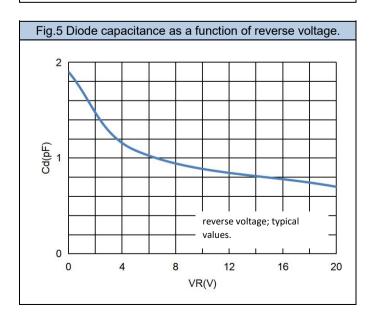
Parameters	Symbol	Cindition	Min	TYP	Max	Unit
		I _F = 1 mA	-	-	0.9	V
Converd Voltage	\/	I _F = 10 mA			1	
Forward Voltage	V _F	I _F = 50 mA			1.1	
		I _F = 150 mA			1.25	
Reverse Current		VR = 75 V	-	3	5	nA
Reverse Current	I _R	VR = 75 V, TJ = 150℃		3	80	nA
Diode Capacitance	C _d	VR = 0 V, f = 1 MHz	1	2	1	pF
Reverse Recovery Time	t _{rr}	IF=IR=10mA,Irr=0.1IR, RL=100Ω	-	0.8	3	ns

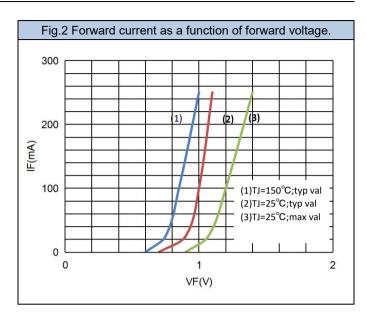


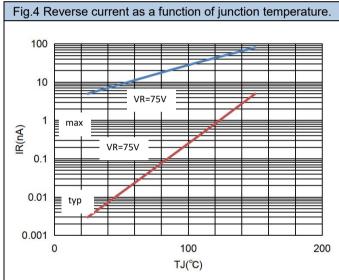
5. Rating And Characteristic Curves







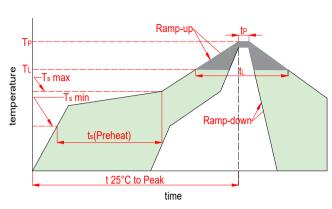






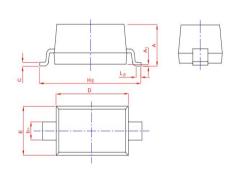
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6. Soldering Parameters

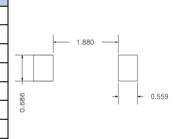


	Reflow Condition	Lead-free
	Temp. min(T _s (min))	150℃
Pre Heat	Temp. max(T _s (min))	200℃
	Time(min to max)(t _s)	60~120s
Aver. ramp up rate(Liquidus Temp.)(T _L)to peak		3℃/s max
T _S (max) to T _L -Ramp-up Rate		3℃/s max
Doflow	Temp.(T _L)(Liquidus)	217℃
Reflow	Temp.(t _L)(Liquidus)	60~150s
Peak Temp.(T _P)		260 ^{+0/-5} ℃
Time within actual peak Temp.(t _p)		30s max
Ramp-down Rate		6℃/s max
Time 25℃ to peak Tempe.(T _p)		8 minutes max
Do not exceed		260℃

7. Dimensions

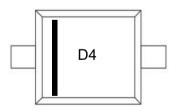


Dimensions	Inches		Millimeters		
Diffictisions	Min	Max	Min	Max	
А	0.031	0.047	0.800	1.200	
bp	0.010	0.016	0.250	0.400	
С	0.003	0.006	0.080	0.150	
D	0.063	0.071	1.600	1.800	
E	0.045	0.055	1.150	1.400	
H _E	0.091	0.110	2.300	2.800	
A1	0.000	0.004	0.010	0.100	
L _P	0.008	0.020	0.200	0.500	



Mounting PAD Layout

8. Part Marking System



9. Package Information

Package	Туре	Tape Width (mm)	Quantity(pcs)
SOD323	BAS416WS	8	3000







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